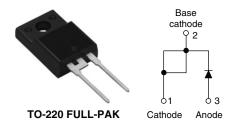


Vishay High Power Products

Input Rectifier Diode, 20 A



PRODUCT SUMMARY			
V _F at 10 A	< 1 V		
I _{FSM}	300 A		
V_{RRM}	800/1200 V		

DESCRIPTION/FEATURES

Available
RoHS*

The 20ETS..FPPbF rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 °C junction temperature.

Typical applications are in input rectification and these products are designed to be used with Vishay HPP switches and output rectifiers which are available in identical package outlines.

Fully isolated package (V_{INS} = 2500 V_{RMS}) is UL E78996 approved

This product has been designed and qualified for industrial level and lead (Pb)-free.

OUTPUT CURRENT IN TYPICAL APPLICATIONS				
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS	
Capacitive input filter T_A = 55 °C, T_J = 125 °C common heatsink of 1 °C/W	18	22	А	

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Sinusoidal waveform	20	Α		
V _{RRM}	Range	800/1200	V		
I _{FSM}		300	Α		
V _F	10 A, T _J = 25 °C	1.0	V		
T _J		- 40 to 150	°C		

VOLTAGE RATINGS						
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA			
20ETS08FPPbF	800	900	1			
20ETS12FPPbF	1200	1300	ı			

ABSOLUTE MAXIMUM RATIN	GS			
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	I _{F(AV)}	$T_C = 51$ °C, 180° conduction half sine wave	20	
Maximum peak one cycle		10 ms sine pulse, rated $V_{\mbox{\scriptsize RRM}}$ applied	250	Α
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	300	
Maximum I ² t for fusing I ² t	10 ms sine pulse, rated $V_{\mbox{\scriptsize RRM}}$ applied	316	A ² s	
	1-1	10 ms sine pulse, no voltage reapplied	442	A-S
Maximum I ² √t for fusing	I²√t	t = 0.1 to 10 ms, no voltage reapplied	4420	A²√s

^{*} Pb containing terminations are not RoHS compliant, exemptions may apply

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST	CONDITIONS	VALUES	UNITS
Maximum forward voltage drop	V_{FM}	20 A, T _J = 25 °C		1.1	V
Forward slope resistance	r _t	T _{.1} = 150 °C		10.4	mΩ
Threshold voltage	V _{F(TO)}			0.85	V
Maximum reverse leakage current		T _J = 25 °C	V _B = Rated V _{BBM}	0.1	mA
Maximum reverse leakage current	IRM	T _J = 150 °C	VR = naleu VRRM	1.0	IIIA

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage tempera	ature range	T _J , T _{Stg}		- 40 to 150	°C
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	2.8	
Maximum thermal resistance, junction to ambient		R_{thJA}		62	°C/W
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.5	
Approximate weight				2	g
Approximate weight				0.07	OZ.
Mounting torque —	minimum			6.0 (5.0)	kgf ⋅ cm
	maximum			12 (10)	(lbf · in)
Marking device			Case style TO-220 FULL-PAK (94/V0)	20ETS 20ETS	

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Input Rectifier Diode, 20 A Vishay High Power Products

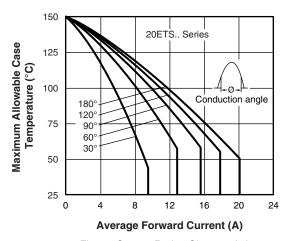


Fig. 1 - Current Rating Characteristics

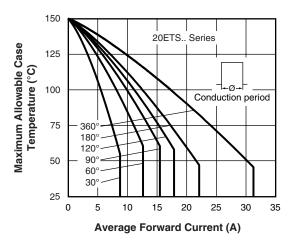


Fig. 2 - Current Rating Characteristics

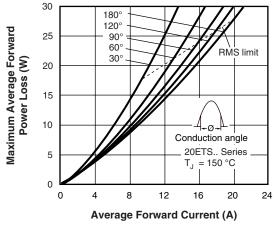


Fig. 3 - Forward Power Loss Characteristics

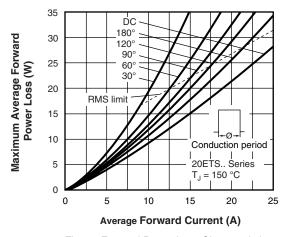
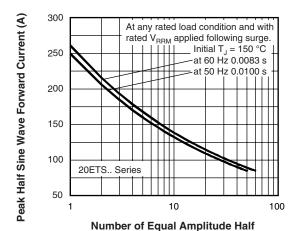


Fig. 4 - Forward Power Loss Characteristics



Cycle Current Pulses (N)
Fig. 5 - Maximum Non-Repetitive Surge Current

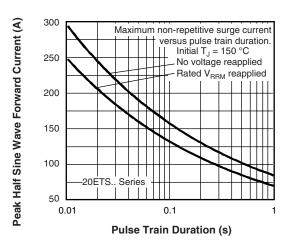


Fig. 6 - Maximum Non-Repetitive Surge Current

Vishay High Power Products Input Rectifier Diode, 20 A



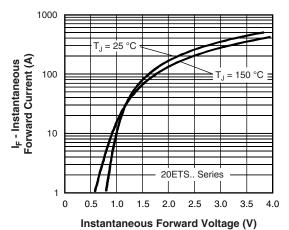


Fig. 7 - Forward Voltage Drop Characteristics

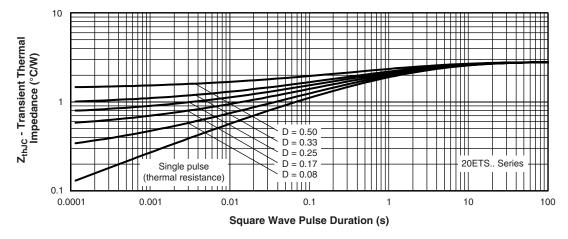


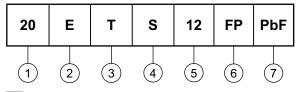
Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



Input Rectifier Diode, 20 A Vishay High Power Products

ORDERING INFORMATION TABLE

Device code



1 - Current rating (20 = 20 A)

2 - Circuit configuration:

E = Single diode

3 - Package:

T = TO-220

4 - Type of silicon:

S = Standard recovery rectifier

08 = 800 V 12 = 1200 V

Voltage ratings

6 - FULL-PAK

None = Standard production

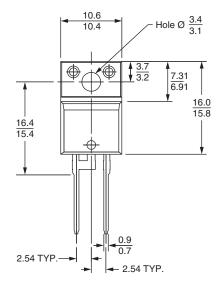
• PbF = Lead (Pb)-free

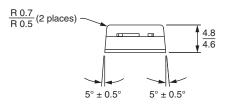
LINKS TO RELATED DOCUMENTS			
Dimensions http://www.vishay.com/doc?95005			
Part marking information	http://www.vishay.com/doc?95009		

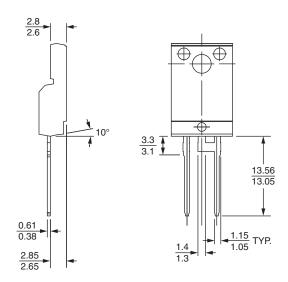
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Vishay Semiconductors

DIMENSIONS in millimeters







Lead assignments

Diodes

1 + 2 - Cathode

3 - Anode

Conforms to JEDEC outline TO-220 FULL-PAK





Vishay

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